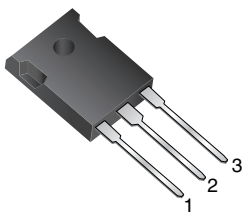
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FEP30AP thru FEP30JP

Vishay General Semiconductor

Dual Common Cathode Ultrafast Rectifier



TO-247AD (TO-3P)



FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low thermal resistance
- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Pb e3 **RoHS** COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, dc-to-dc converters, and other power switching application.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	30 A
V_{RRM}	50 V to 600 V
I_{FSM}	300 A
t_{rr}	35 ns, 50 ns
V_F	0.95 V, 1.3 V, 1.5 V
T_J max.	150 °C

MECHANICAL DATA

Case: TO-247AD (TO-3P)
Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102
E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	FEP 30AP	FEP 30BP	FEP 30CP	FEP 30DP	FEP 30FP	FEP 30GP	FEP 30HP	FEP 30JP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current at T_C = 100 °C	$I_{F(AV)}$	30								A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	300								A
Operating storage and temperature range	T_J, T_{STG}	- 55 to + 150								°C/W

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)											
PARAMETER	TEST CONDITIONS	SYMBOL	FEP 30AP	FEP 30BP	FEP 30CP	FEP 30DP	FEP 30FP	FEP 30GP	FEP 30HP	FEP 30JP	UNIT
Maximum instantaneous forward voltage per diode	15.0 A	V_F	0.95				1.3		1.5		V
Maximum DC reverse current at rated DC blocking voltage per diode	T_C = 25 °C	I_R	10								μA
	T_C = 100 °C		500								
Maximum reverse recovery time per diode	I_F = 0.5 A, I_R = 1.0 A, I_{rr} = 0.25 A	t_{rr}	35				50				ns
Typical junction capacitance per diode	4.0 V, 1 MHz	C_J	175						145		pF

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FEP 30AP	FEP 30BP	FEP 30CP	FEP 30DP	FEP 30FP	FEP 30GP	FEP 30HP	FEP 30JP	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$ (1)	1.0								°C/W

Note

(1) Thermal resistance from junction to case per diode mounted on heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-247AD	FEP30JP-E3/45	6.15	30	30/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

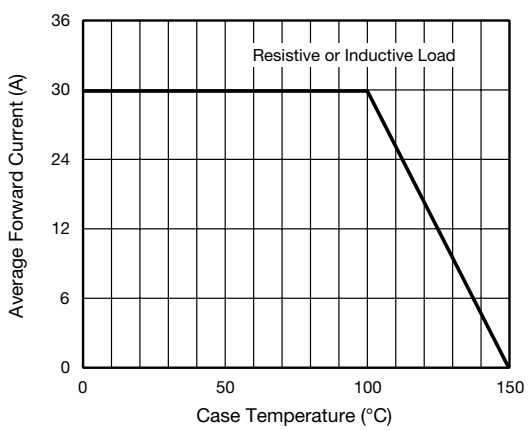


Fig. 1 - Forward Current Derating Curve

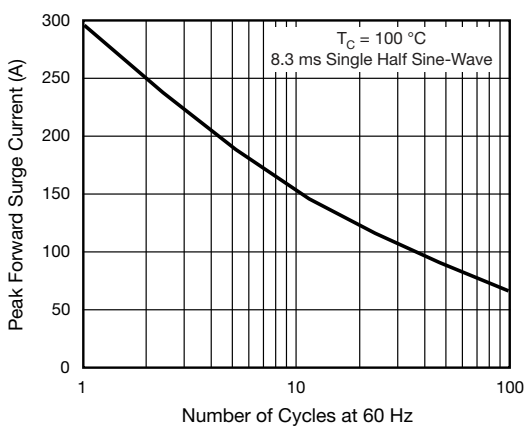


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

For technical questions within your region, please contact one of the following:
DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
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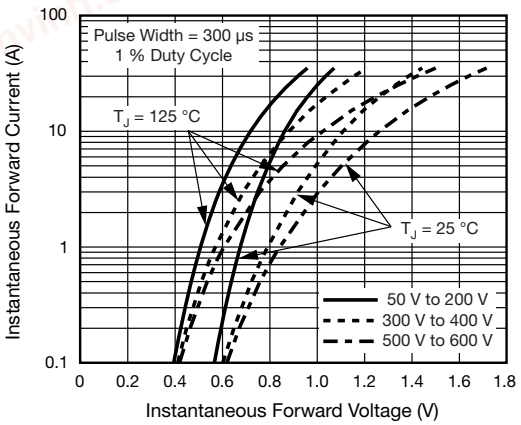


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

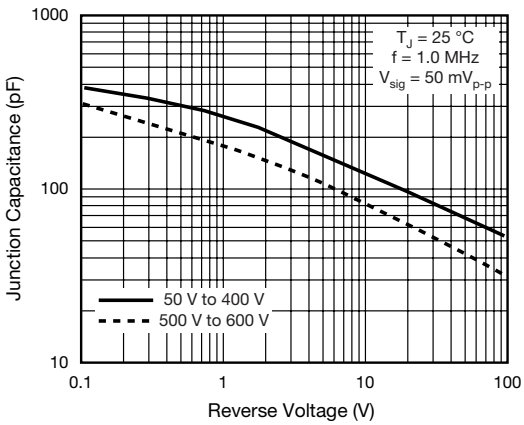


Fig. 5 - Typical Junction Capacitance Per Diode

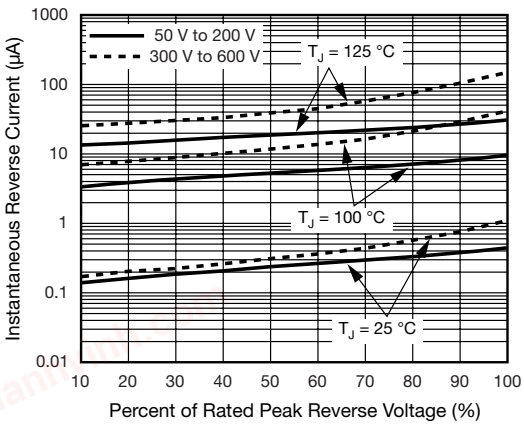
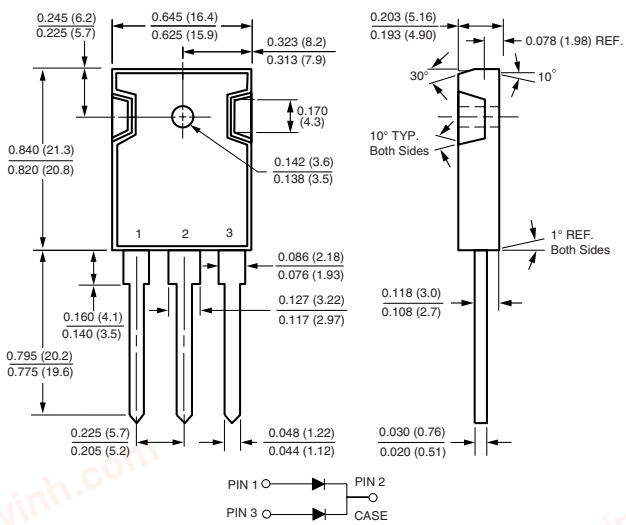


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)



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